

SN74LVC1G74 クリア / プリセット搭載、シングル・ポジティブ・エッジ・トリガ型 D-Type フリップ・フロップ

1 特長

- テキサス・インスツルメンツの NanoFree™ パッケージで提供
- 5V V_{CC} 動作をサポート
- 5.5V までの入力電圧に対応
- V_{CC} への降圧変換をサポート
- 最大 t_{pd} : 5.9ns (3.3V 時)
- 低消費電力、最大 I_{CC} : 10 μ A
- 3.3V において ± 24 mA の出力駆動能力
- 標準 V_{OLP} (出力グランド・バウンス)
< 0.8V ($V_{CC} = 3.3$ V, $T_A = 25^\circ$ C)
- 標準 V_{OHV} (出力 V_{OH} アンダーシュート)
> 2V ($V_{CC} = 3.3$ V, $T_A = 25^\circ$ C)
- I_{off} により活線挿抜、部分的パワーダウン・モード、バック・ドライブ保護をサポート
- JESD 78、Class II 準拠で 100mA 超のラッチアップ性能
- JESD 22 を超える ESD 保護
 - 人体モデルで 2000V
 - マシン・モデルで 200V
 - デバイス帯電モデルで 1000V

2 アプリケーション

- サーバー
- LED ディスプレイ
- ネットワーク・スイッチ
- 通信インフラ
- モーター・ドライバ
- I/O エクスパンダ

3 概要

このシングル・ポジティブ・エッジ・トリガ D タイプ・フリップ・フロップは、1.65V～5.5V の V_{CC} で動作するように設計されています。

ダイをパッケージとして使用する NanoFree™ パッケージ技術は、IC パッケージの概念を大きく覆すものです。

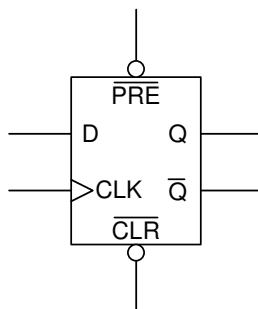
その他の入力のレベルに関係なく、プリセット ($\overline{PRE}$) 入力を LOW レベルにすると出力は HIGH になり、クリア ($\overline{CLR}$) 入力を LOW レベルにすると出力は LOW になります。 $\overline{PRE}$ と $\overline{CLR}$ が非アクティブ (HIGH) の場合、セットアップ時間の要件を満たすデータ (D) 入力のデータは、クロック・パルスの正方向エッジで出力に転送されます。クロックのトリガは電圧レベルで発生し、クロック・パルスの立ち上がり時間とは直接関係しません。ホールド時間が経過した後、D 入力のデータは、出力のレベルに影響を及ぼさずに変化させることができます。

このデバイスは、 I_{off} を使用する部分的パワーダウン・アプリケーション用の動作が完全に規定されています。 I_{off} 回路が出力をディスエーブルにするため、電源切断時にデバイスに電流が逆流して損傷に至ることを回避できます。

製品情報

部品番号	パッケージ ⁽¹⁾	本体サイズ
SN74LVC1G74	SM8 (8)	2.95mm × 2.80mm
	US8 (8)	2.30mm × 2.00mm
	X2SON (8)	1.40mm × 1.00mm
	UQFN (8)	1.50mm × 1.50mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。



概略回路図



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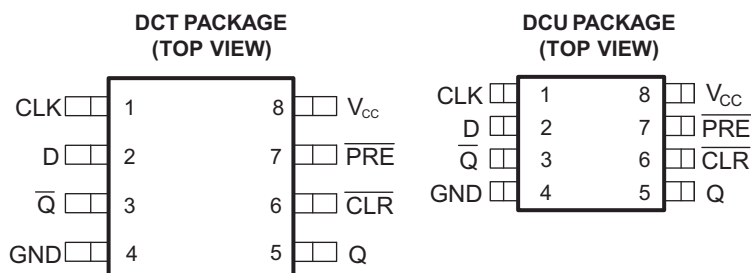
4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision F (April 2020) to Revision G (September 2021)	Page
• 文書全体にわたって表、図、相互参照の採番方法を更新.....	1
• Updated the <i>Application and Information</i> section.....	11
• Updated the <i>Device Power Button Circuit</i> figure <i>Typical Power Button Circuit</i> section.....	11
Changes from Revision E (January 2015) to Revision F (April 2020)	Page
• Match RSE pinout with signal names.....	4
Changes from Revision D (January 2013) to Revision E (January 2015)	Page
• 「アプリケーション」セクション、「製品情報」表、「端子機能」表、「ESD 定格」表、「熱に関する情報」表、「{代表的特性{」セクション、「{機能説明{」セクション、「{デバイスの機能モード{」セクション、「{アプリケーションと実装{」セクション、「{電源に関する推奨事項{」セクション、「{レイアウト{」セクション、「{デバイスおよびドキュメントのサポート{」セクション、「{メカニカル、パッケージ、および注文情報{」セクションを追加.....	1
• 「注文情報」表を削除.....	1
• 「特長」を更新.....	1
Changes from Revision C (November 2012) to Revision D (January 2013)	Page
• DQE パッケージの熱特性データを削除.....	1
• Added Thermal data for DQE Package.....	6
Changes from Revision B (March 2012) to Revision C (November 2012)	Page
• RES 部品のプレビューを追加.....	1
• Added QFN package ordering information.....	14
Changes from Revision A (November 2011) to Revision B (February 2012)	Page
• Added SN74LVC1G74DCURG4 part number to ORDERING INFORMATION table.....	14
Changes from Revision * (October 2009) to Revision A (November 2011)	Page
• 「特長」の I_{off} の説明を変更.....	1

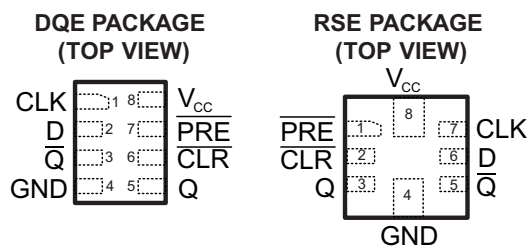
• Changed temperature range for DCT and DCU package from (–40°C to 85°C) to (–40°C to 125°C).....	6
• Changed <i>Timing Requirements</i> table.....	7
• Changed <i>Switching Requirements</i> table.....	7

5 Pin Configuration and Functions



See mechanical drawings for dimensions.

FIG 5-1. DCT 8-Pin SM8 and DCU 8-Pin VSSOP Package Top View



See mechanical drawings for dimensions

FIG 5-2. DQE 8-Pin X2SON and RSE UQFN 8-Pin Package Top View

Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
CLK	1	I	Clock input
$\overline{\text{CLR}}$	6	I	Clear input – Pull low to set Q output low
D	2	I	Input
GND	4	—	Ground
$\overline{\text{PRE}}$	7	I	Preset input – Pull low to set Q output high
Q	5	O	Output
$\overline{\text{Q}}$	3	O	Inverted output
V _{CC}	8	—	Supply

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage range	–0.5	6.5	V
V _I	Input voltage range ⁽²⁾	–0.5	6.5	V
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	–0.5	6.5	V
V _O	Voltage range applied to any output in the high or low state ⁽²⁾ (3)	–0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		–50 mA
I _{OK}	Output clamp current	V _O < 0		–50 mA
I _O	Continuous output current			±50 mA
	Continuous current through V _{CC} or GND			±100 mA
T _{stg}	Storage temperature range	–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

6.2 ESD Ratings

PARAMETER	DEFINITION	VALUE	UNIT
V _(ESD) Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	2000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT	
V _{CC}	Supply voltage	Operating	1.65	5.5	V	
		Data retention only	1.5			
V _{IH}	High-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}		V	
		V _{CC} = 2.3 V to 2.7 V	1.7			
		V _{CC} = 3 V to 3.6 V	2			
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}			
V _{IL}	Low-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.35 × V _{CC}		V	
		V _{CC} = 2.3 V to 2.7 V	0.7			
		V _{CC} = 3 V to 3.6 V	0.8			
		V _{CC} = 4.5 V to 5.5 V	0.3 × V _{CC}			
V _I	Input voltage		0	5.5	V	
V _O	Output voltage		0	V _{CC}	V	
I _{OH}	High-level output current	V _{CC} = 1.65 V		−4	mA	
		V _{CC} = 2.3 V		−8		
		V _{CC} = 3 V		−16		
				−24		
		V _{CC} = 4.5 V		−32		
I _{OL}	Low-level output current	V _{CC} = 1.65 V		4	mA	
		V _{CC} = 2.3 V		8		
		V _{CC} = 3 V		16		
				24		
		V _{CC} = 4.5 V		32		
Δt/Δv	Input transition rise or fall rate	V _{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	ns/V	
		V _{CC} = 3.3 V ± 0.3 V		10		
		V _{CC} = 5 V ± 0.5 V		5		
T _A	Operating free-air temperature	RSE Package	−40	85	°C	
		DQE Package				
		DCT Package	−40	125		
		DCU Package				

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74LVC1G74				UNIT
		DCT	DCU	RSE	DQE	
		8 PINS	8 PINS	8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	220	227	243	261	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}		I _{OH} = –100 µA	1.65 V to 5.5 V	V _{CC} – 0.1			V
		I _{OH} = –4 mA	1.65 V	1.2			
		I _{OH} = –8 mA	2.3 V	1.9			
		I _{OH} = –16 mA	3 V	2.4			
		I _{OH} = –24 mA		2.3			
		I _{OH} = –32 mA	4.5 V	3.8			
V _{OL}		I _{OL} = 100 µA	1.65 V to 5.5 V	0.1			V
		I _{OL} = 4 mA	1.65 V	0.45			
		I _{OL} = 8 mA	2.3 V	0.3			
		I _{OL} = 16 mA	3 V	0.4			
		I _{OL} = 24 mA		0.55			
		I _{OL} = 32 mA	4.5 V	0.55			
I _I	Data or control inputs	V _I = 5.5 V or GND	0 to 5.5 V	±5			µA
I _{off}		V _I or V _O = 5.5 V	0	±10			µA
I _{CC}		V _I = 5.5 V or GND, I _O = 0	1.65 V to 5.5 V	10			µA
ΔI _{CC}		One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	3 V to 5.5 V	500			µA
C _i		V _I = V _{CC} or GND	3.3 V	5			pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

6.6 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 7-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	–40°C to 85°C								–40°C to 125°C						UNIT
			V _{CC} = 1.8 V		V _{CC} = 2.5 V		V _{CC} = 3.3 V		V _{CC} = 5 V		V _{CC} = 3.3 V		V _{CC} = 5 V				
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
f _{clock}			80		175		175		200		175		200		MHz		
t _w	CLK		6.2		2.7		2.7		2		2.7		2		ns		
	PRE or CLR low		6.2		2.7		2.7		2		2.7		2				
t _{su}	Data		2.9		1.7		1.3		1.1		1.3		1.1		ns		
	PRE or CLR inactive		1.9		1.4		1.2		1		1.2		1.2				
t _h			0		0.3		1.2		0.5		1.2		0.5		ns		

6.7 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 7-1](#))

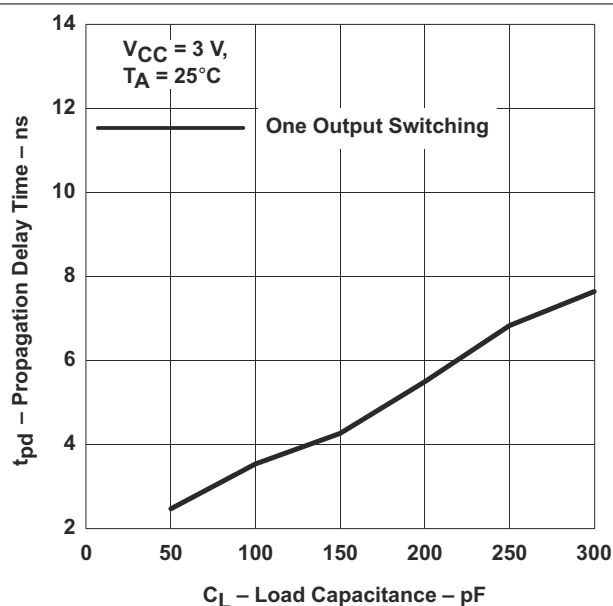
PARAMETER	FROM (INPUT)	TO (OUTPUT)	–40°C to 85°C								–40°C to 125°C				UNIT
			V _{CC} = 1.8 V		V _{CC} = 2.5 V		V _{CC} = 3.3 V		V _{CC} = 5 V		V _{CC} = 3.3 V		V _{CC} = 5 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			80		175		175		200		175		200		MHz
t _{pd}	CLK	Q	4.8	13.4	2.2	7.1	2.2	5.9	1.4	4.1	2.2	7.9	1.4	6.1	ns
		$\overline{Q}$	6	14.4	3	7.7	2.6	6.2	1.6	4.4	2.6	8.2	1.6	6.4	
	PRE or $\overline{CLR}$ low	Q or $\overline{Q}$	4.4	12.9	2.3	7	1.7	5.9	1.6	4.1	1.7	7.9	1.6	6.1	

6.8 Operating Characteristics

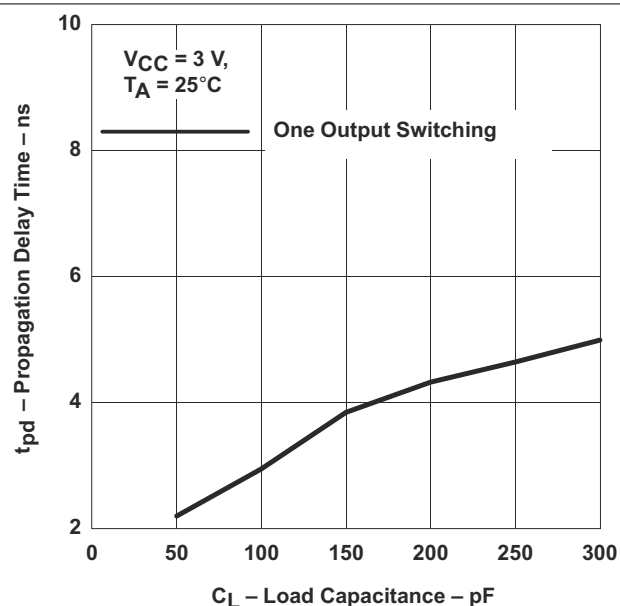
 $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	$V_{CC} = 1.8\text{ V}$	$V_{CC} = 2.5\text{ V}$	$V_{CC} = 3.3\text{ V}$	$V_{CC} = 5\text{ V}$	UNIT
		TYP	TYP	TYP	TYP	
C_{pd} Power dissipation capacitance	$f = 10\text{ MHz}$	35	35	37	40	pF

6.9 Typical Characteristics

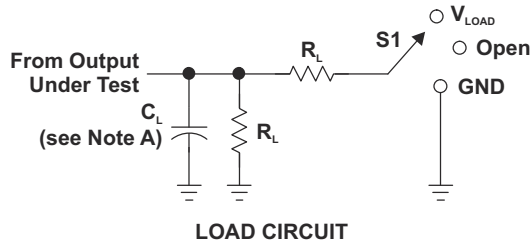


6-1. Propagation Delay (Low to High Transition) vs Load Capacitance



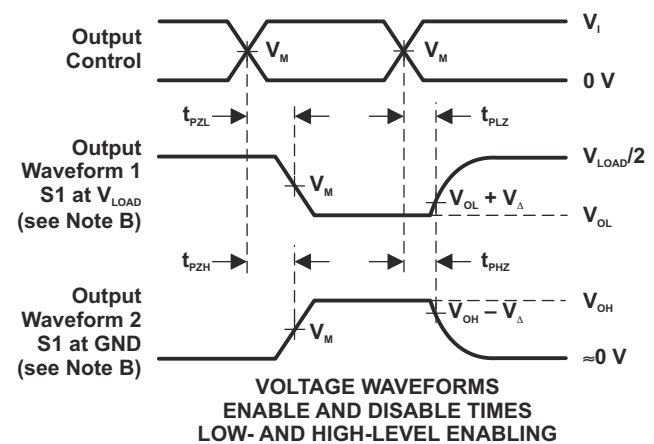
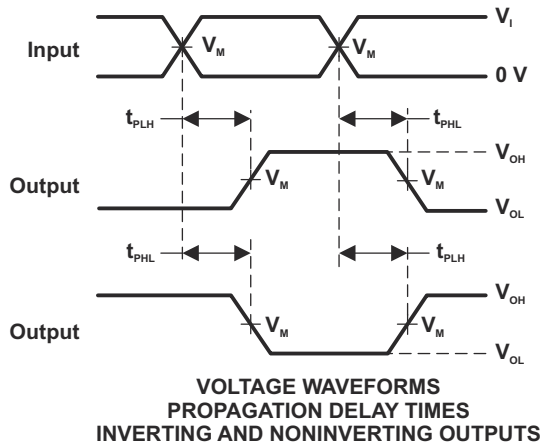
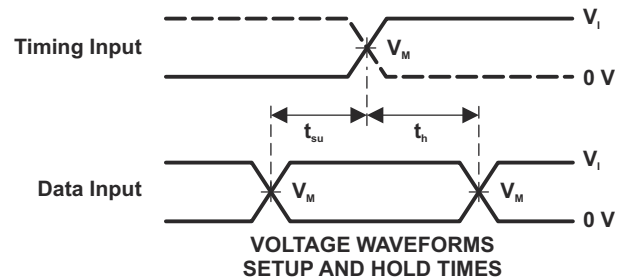
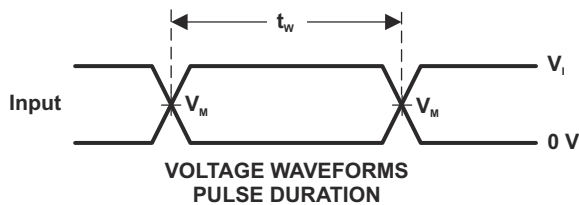
6-2. Propagation Delay (High to Low Transition) vs Load Capacitance

7 Parameter Measurement Information



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_I	t_r/t_f					
$1.8\text{ V} \pm 0.15\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$2.5\text{ V} \pm 0.2\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
$3.3\text{ V} \pm 0.3\text{ V}$	3 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V
$5\text{ V} \pm 0.5\text{ V}$	V_{CC}	$\leq 2.5\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: PRR $\leq 10\text{ MHz}$, $Z_o = 50\ \Omega$.
 - The outputs are measured one at a time, with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .
 - All parameters and waveforms are not applicable to all devices.

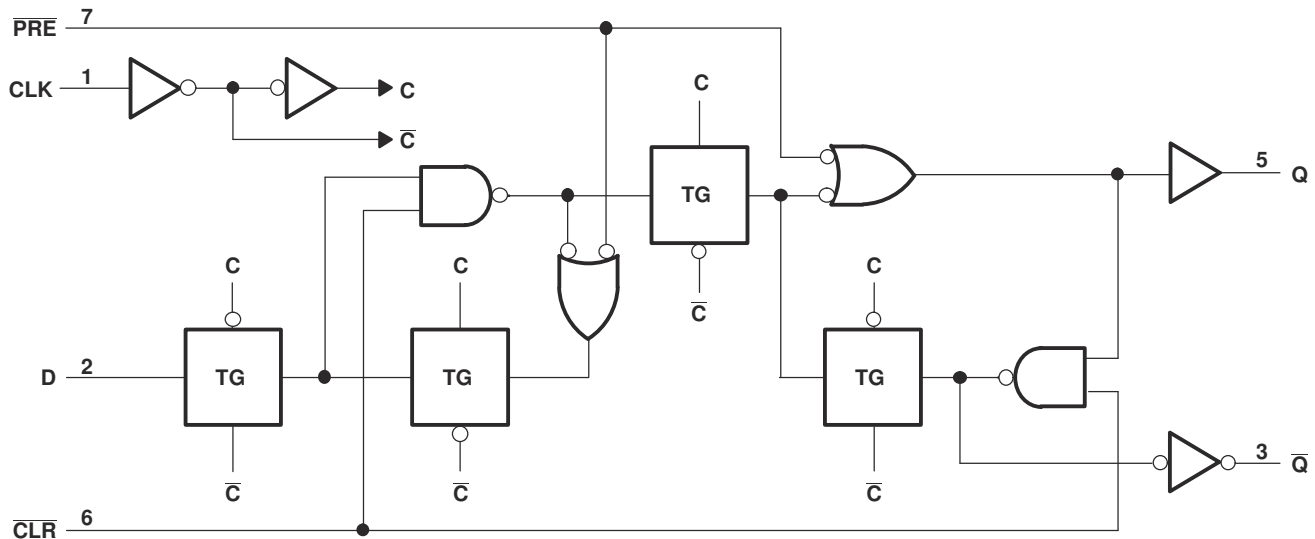
7-1. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

8.2 Functional Block Diagram



8.3 Feature Description

- Allow down voltage translation
 - 5-V to 3.3-V
 - 5.0-V to 1.8-V
 - 3.3-V to 1.8-V
- Inputs accept voltage levels up to 5.5-V
- I_{off} Feature
 - Can prevent backflow current that can damage device when powered down

8.4 Device Functional Modes

表 8-1. Function Table

INPUTS				OUTPUTS	
PRE	CLR	CLK	D	Q	$\bar{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H ⁽¹⁾	H ⁽¹⁾
H	H	↑	H	H	L
H	H	↑	L	L	H
H	H	L	X	Q_0	$\bar{Q}_0$

(1) This configuration is nonstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.

9 Application and Implementation

Note

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

9.1 Application Information

A low level at the preset ($\overline{\text{PRE}}$) or clear ($\overline{\text{CLR}}$) input sets or resets the outputs, regardless of the levels of the other inputs. When $\overline{\text{PRE}}$ and $\overline{\text{CLR}}$ are inactive (high), data at the data (D) input meeting the setup time requirements is transferred to the outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not related directly to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

The 330 Ω resistor and 22 pF capacitor shown in [Figure 9-1](#) produce enough delay to meet the hold time requirement of the D input. To calculate the delay for a particular RC combination, use [Equation 1](#). The delay with this RC combination is 5.03 ns

$$t_{\text{delay}} = -RC \ln(0.5) \approx 0.693 RC \quad (1)$$

To ensure proper operation, check that the transition time of the RC circuit meets the transition time requirements of the device inputs listed in the Recommended Operating Conditions table. Transition time for an RC can be approximated with [Equation 2](#).

$$t_r \approx 2.2 RC \quad (2)$$

9.2 Typical Power Button Circuit

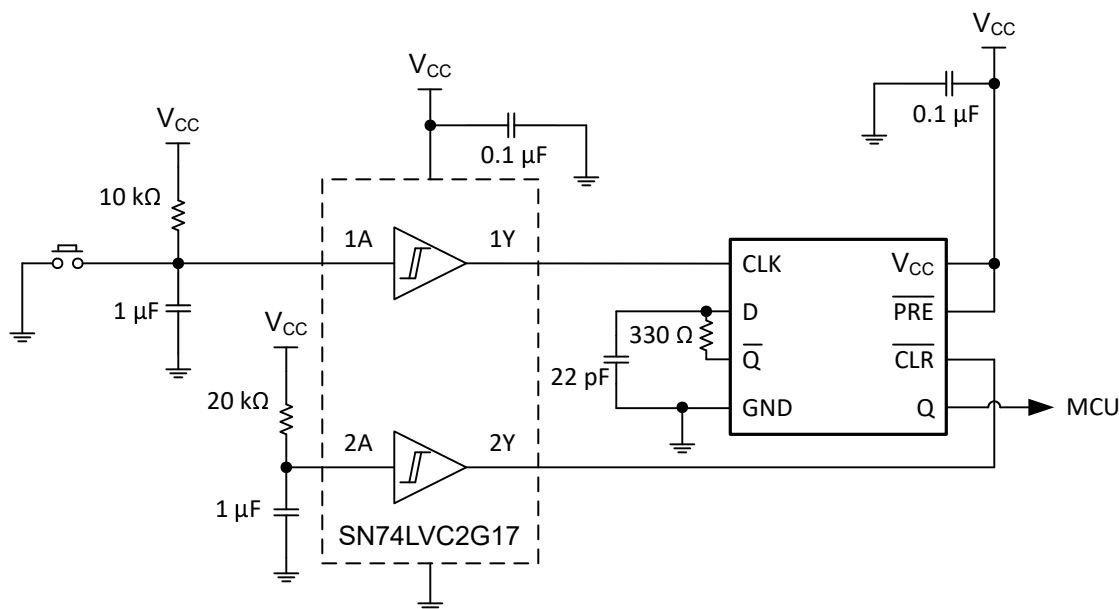


Figure 9-1. Device Power Button Circuit

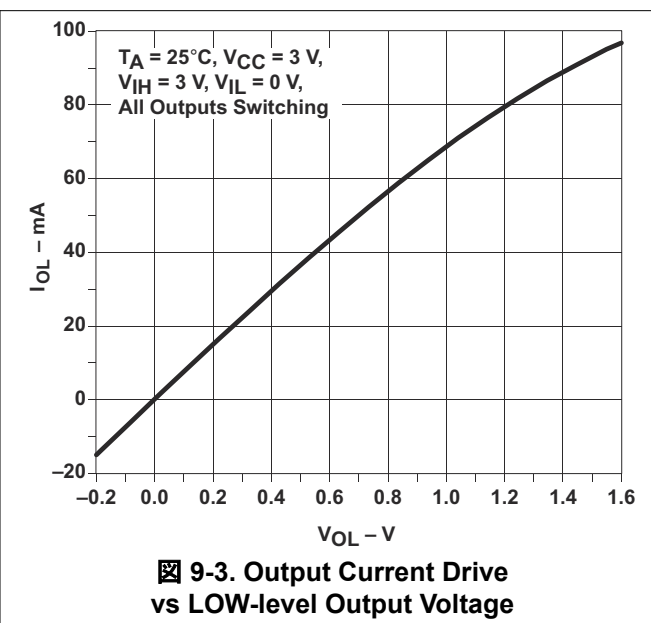
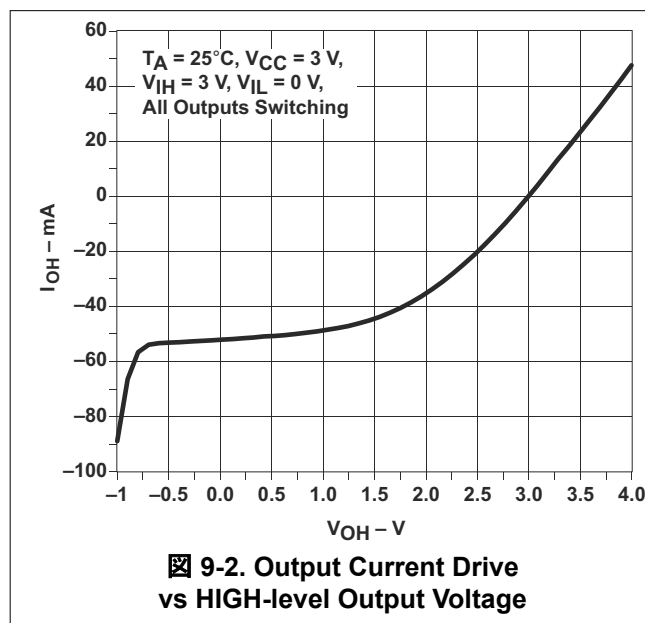
9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. Outputs can be combined to produce higher drive but the high drive will also create faster edges into light loads so routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- Recommended Input Conditions:
 - For rise time and fall time specifications, see $(\Delta t/\Delta V)$ in the [Recommended Operating Conditions](#) table.
 - For specified high and low levels, see $(V_{IH}$ and $V_{IL})$ in the [Recommended Operating Conditions](#) table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5-V at any valid V_{CC} .
- Recommend Output Conditions:
 - Load currents should not exceed 50-mA per output and 100-mA total for the part.
 - Series resistors on the output may be used if the user desires to slow the output edge signal or limit the output current.

9.2.3 Application Curves



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the [Recommended Operating Conditions](#) table. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended and if there are multiple V_{CC} terminals then .01- μ F or .022- μ F capacitors are recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in [Figure 11-1](#) are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

11.2 Layout Example

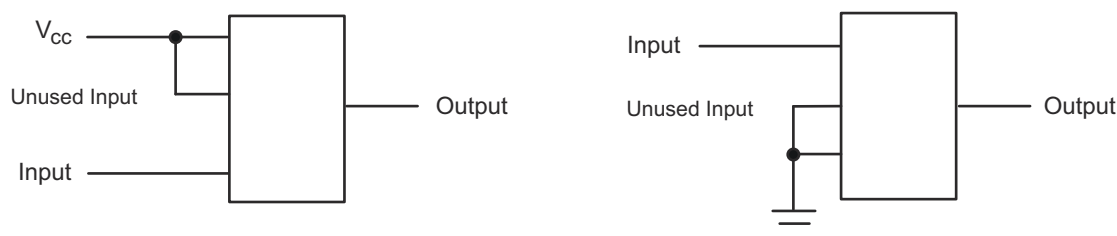


Figure 11-1. Layout Diagram

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 サポート・リソース

[TI E2E™ サポート・フォーラム](#)は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、該当する貢献者により、現状のまま提供されるものです。これらは TI の仕様を構成するものではなく、必ずしも TI の見解を反映したものではありません。TI の[使用条件](#)を参照してください。

12.3 Trademarks

NanoFree™ is a trademark of Texas Instruments.

TI E2E™ is a trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

12.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LVC1G74DCTR	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(2WE5, N74) Z
SN74LVC1G74DCTR.B	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2WE5, N74) Z
SN74LVC1G74DCUR	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(N74J, N74Q, N74R)
SN74LVC1G74DCUR.B	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(N74J, N74Q, N74R)
SN74LVC1G74DCURG4	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	N74R
SN74LVC1G74DCURG4.B	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	N74R
SN74LVC1G74DCUT	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(N74J, N74Q, N74R)
SN74LVC1G74DCUT.B	Active	Production	VSSOP (DCU) 8	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(N74J, N74Q, N74R)
SN74LVC1G74DQER	Active	Production	X2SON (DQE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74DQER.B	Active	Production	X2SON (DQE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74DQERG4	Active	Production	X2SON (DQE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74DQERG4.B	Active	Production	X2SON (DQE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSE2	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSE2.B	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSE2G4	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSE2G4.B	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSER	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSER.B	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSERG4	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP
SN74LVC1G74RSERG4.B	Active	Production	UQFN (RSE) 8	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DP

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

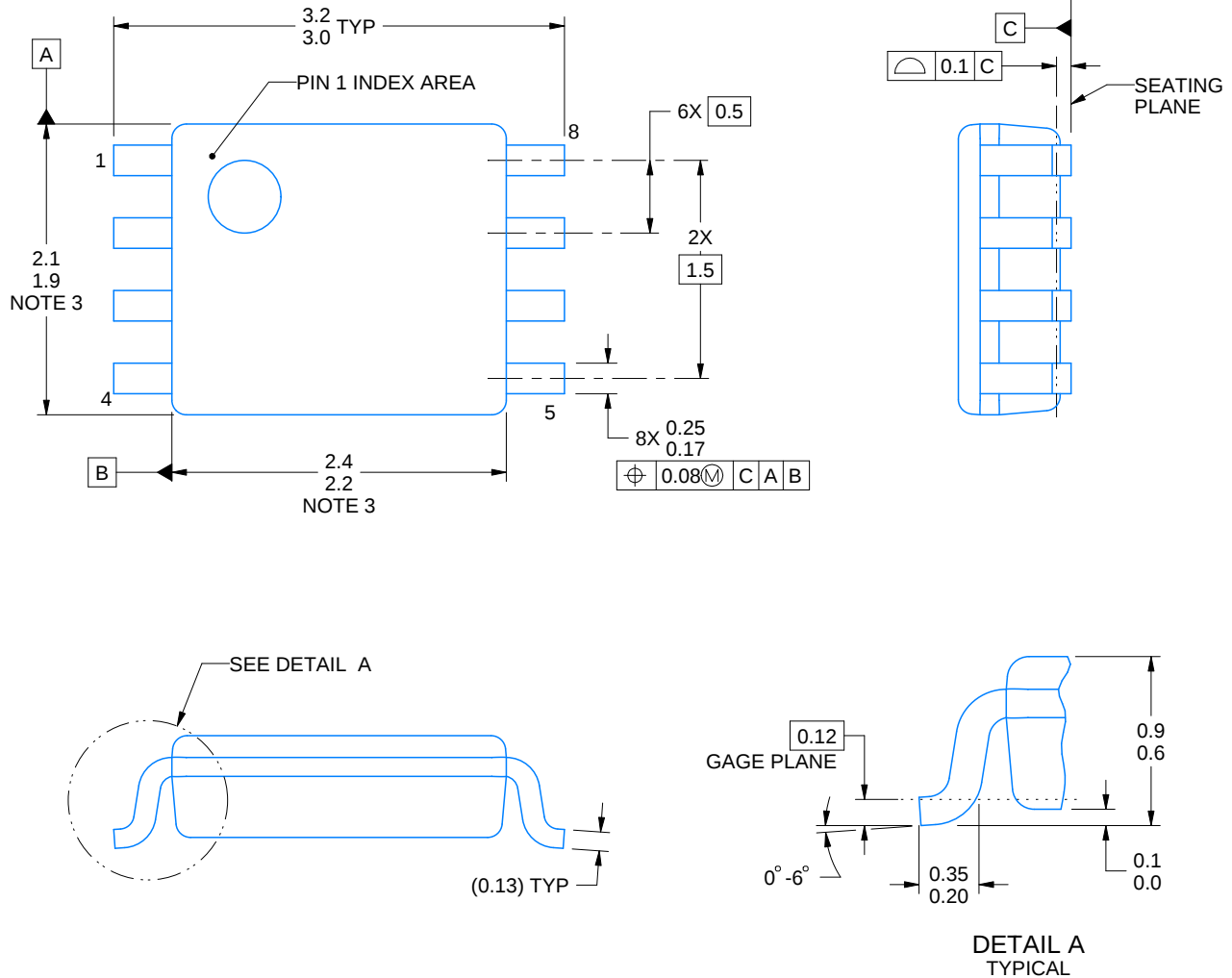
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G74DCTR	SSOP	DCT	8	3000	180.0	12.4	3.15	4.35	1.55	4.0	12.0	Q3
SN74LVC1G74DCUR	VSSOP	DCU	8	3000	178.0	9.0	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC1G74DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC1G74DCUT	VSSOP	DCU	8	250	178.0	9.0	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC1G74DQER	X2SON	DQE	8	5000	180.0	9.5	1.15	1.6	0.5	4.0	8.0	Q1
SN74LVC1G74DQERG4	X2SON	DQE	8	5000	180.0	9.5	1.15	1.6	0.5	4.0	8.0	Q1
SN74LVC1G74RSE2	UQFN	RSE	8	5000	180.0	9.5	1.7	1.7	0.75	4.0	8.0	Q3
SN74LVC1G74RSE2G4	UQFN	RSE	8	5000	180.0	9.5	1.7	1.7	0.75	4.0	8.0	Q3
SN74LVC1G74RSER	UQFN	RSE	8	5000	180.0	9.5	1.7	1.7	0.75	4.0	8.0	Q2
SN74LVC1G74RSERG4	UQFN	RSE	8	5000	180.0	9.5	1.7	1.7	0.75	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G74DCTR	SSOP	DCT	8	3000	190.0	190.0	30.0
SN74LVC1G74DCUR	VSSOP	DCU	8	3000	180.0	180.0	18.0
SN74LVC1G74DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74LVC1G74DCUT	VSSOP	DCU	8	250	180.0	180.0	18.0
SN74LVC1G74DQER	X2SON	DQE	8	5000	184.0	184.0	19.0
SN74LVC1G74DQERG4	X2SON	DQE	8	5000	184.0	184.0	19.0
SN74LVC1G74RSE2	UQFN	RSE	8	5000	184.0	184.0	19.0
SN74LVC1G74RSE2G4	UQFN	RSE	8	5000	184.0	184.0	19.0
SN74LVC1G74RSER	UQFN	RSE	8	5000	184.0	184.0	19.0
SN74LVC1G74RSERG4	UQFN	RSE	8	5000	184.0	184.0	19.0



4225266/A 09/2014

NOTES:

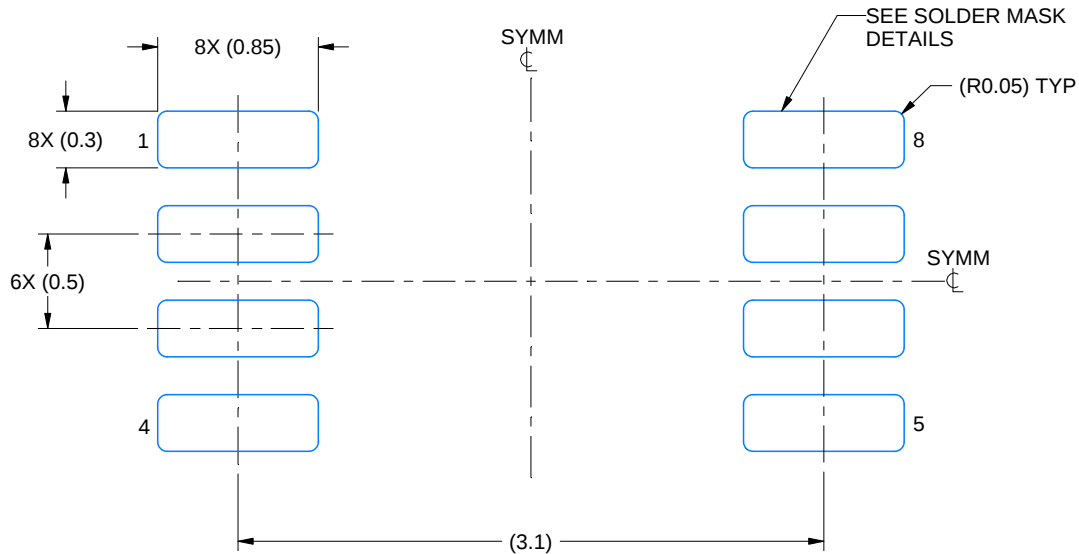
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-187 variation CA.

EXAMPLE BOARD LAYOUT

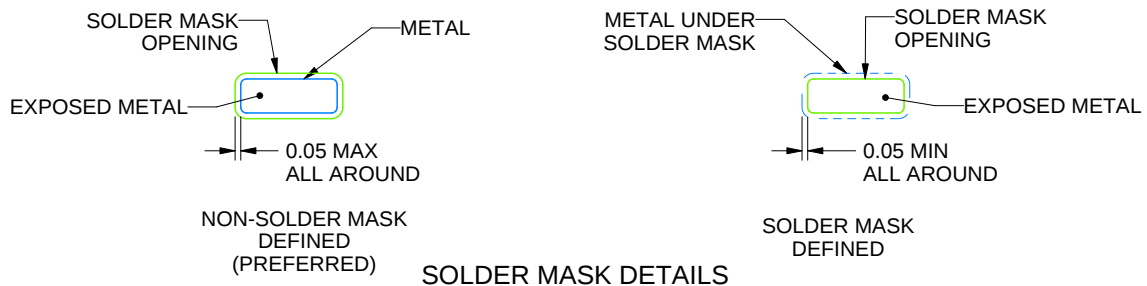
DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X



4225266/A 09/2014

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

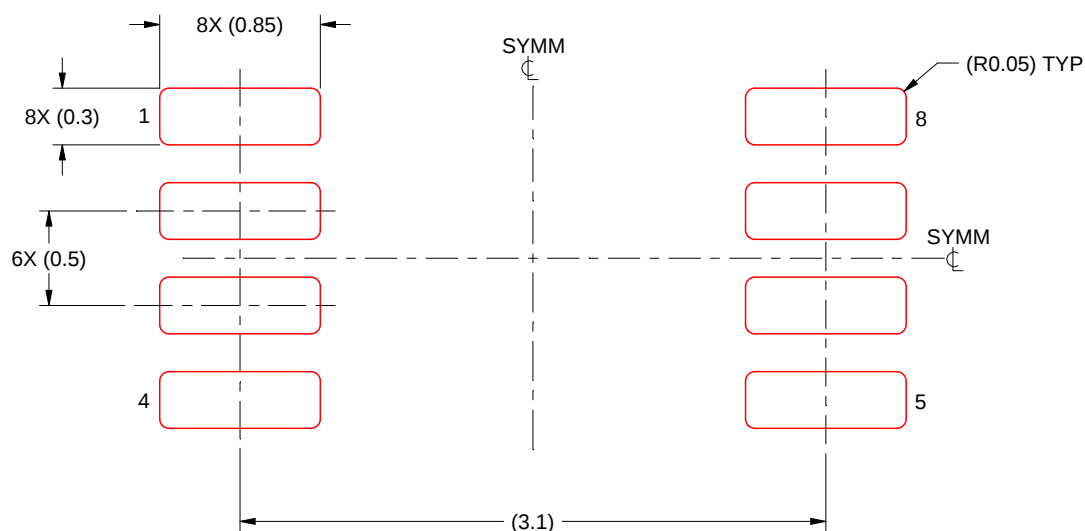
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

4225266/A 09/2014

NOTES: (continued)

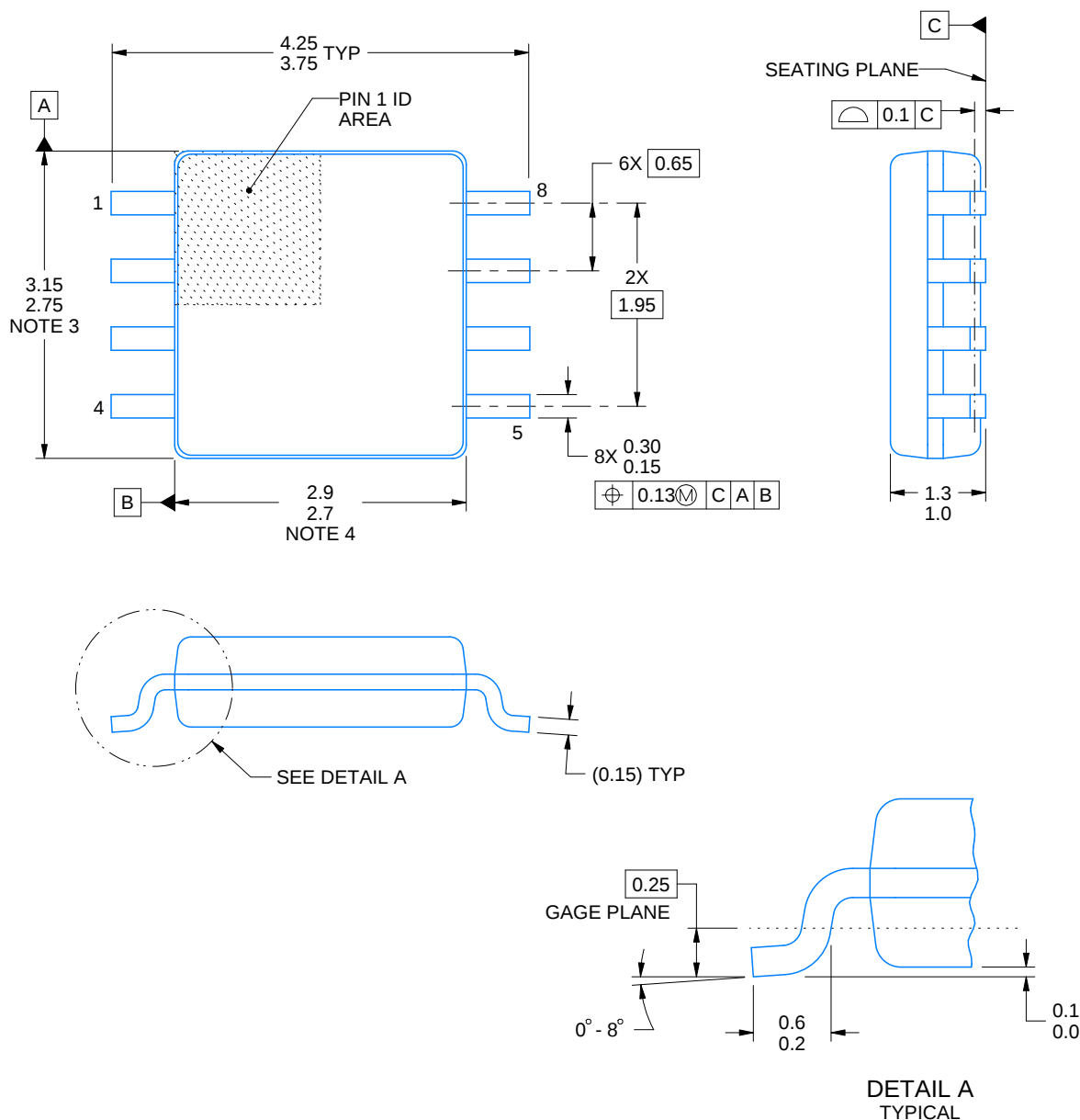
7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



4220784/C 06/2021

NOTES:

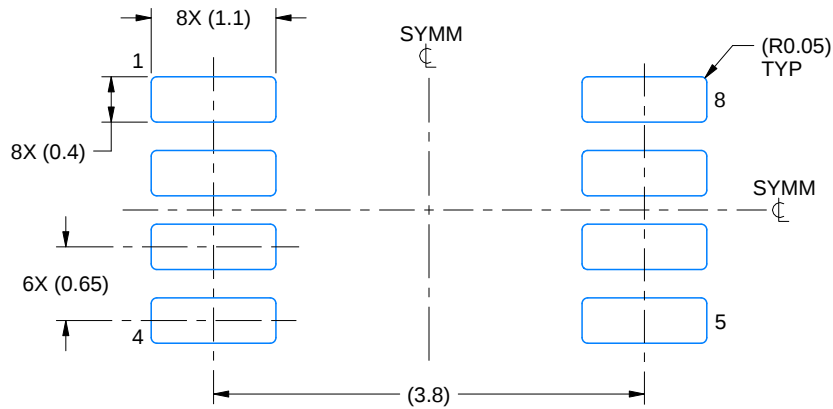
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.

EXAMPLE BOARD LAYOUT

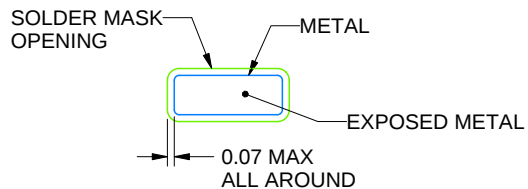
DCT0008A

SSOP - 1.3 mm max height

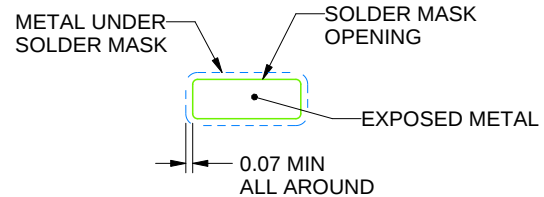
SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



NON SOLDER MASK
DEFINED



SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220784/C 06/2021

NOTES: (continued)

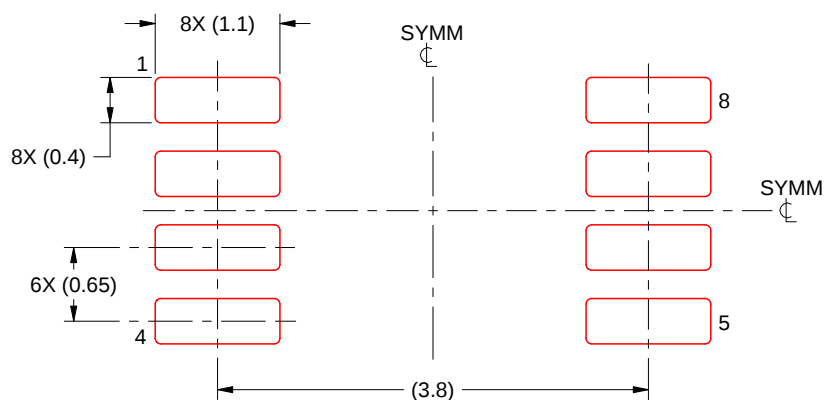
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCT0008A

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE

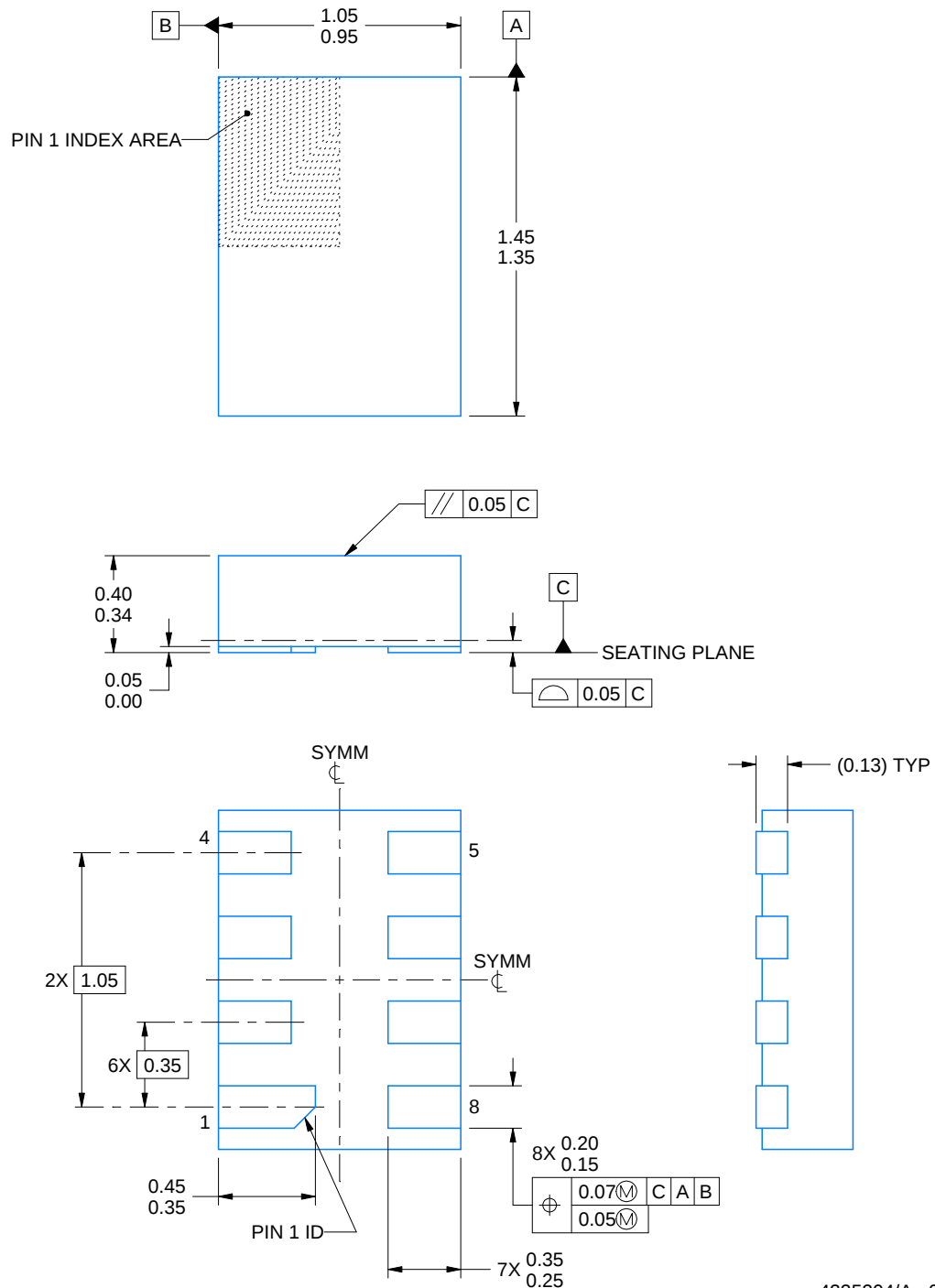
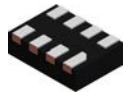


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4220784/C 06/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



4225204/A 08/2019

NOTES:

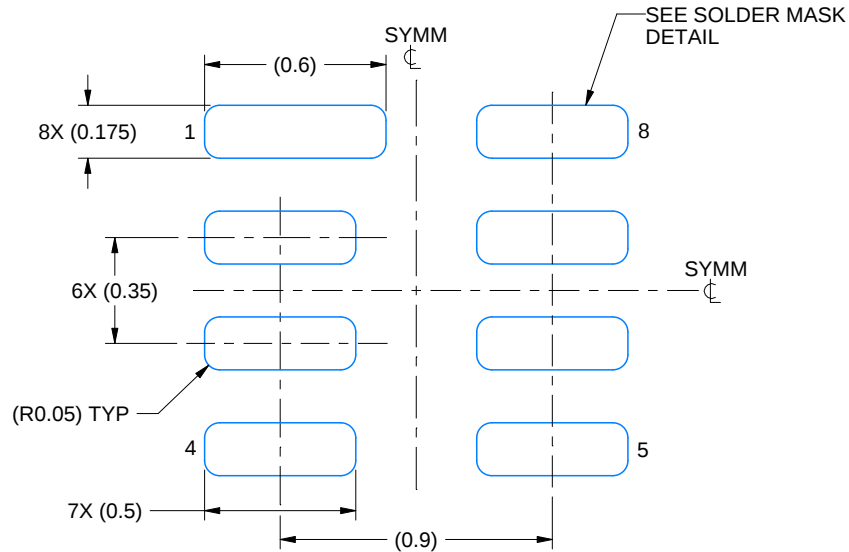
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package complies to JEDEC MO-287 variation X2EAF.

EXAMPLE BOARD LAYOUT

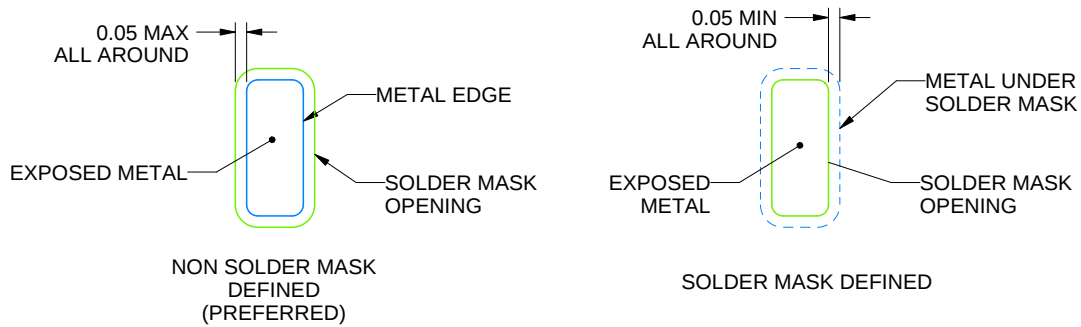
DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 40X



SOLDER MASK DETAILS

4225204/A 08/2019

NOTES: (continued)

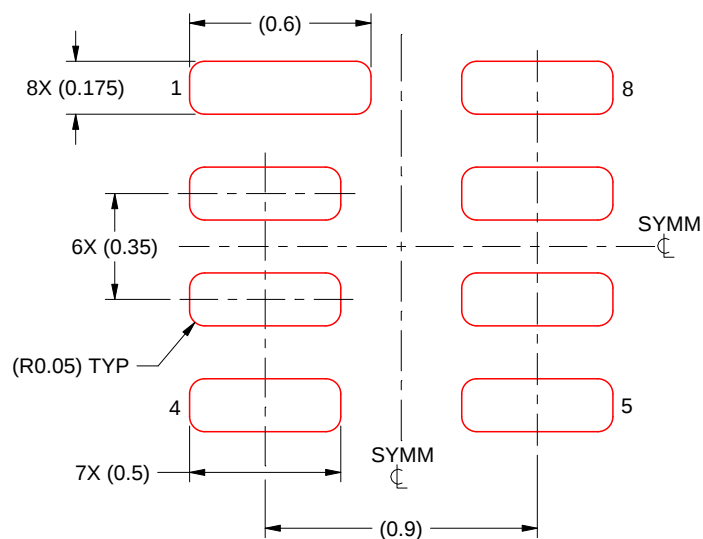
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).

EXAMPLE STENCIL DESIGN

DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 MM THICK STENCIL
SCALE: 40X

4225204/A 08/2019

NOTES: (continued)

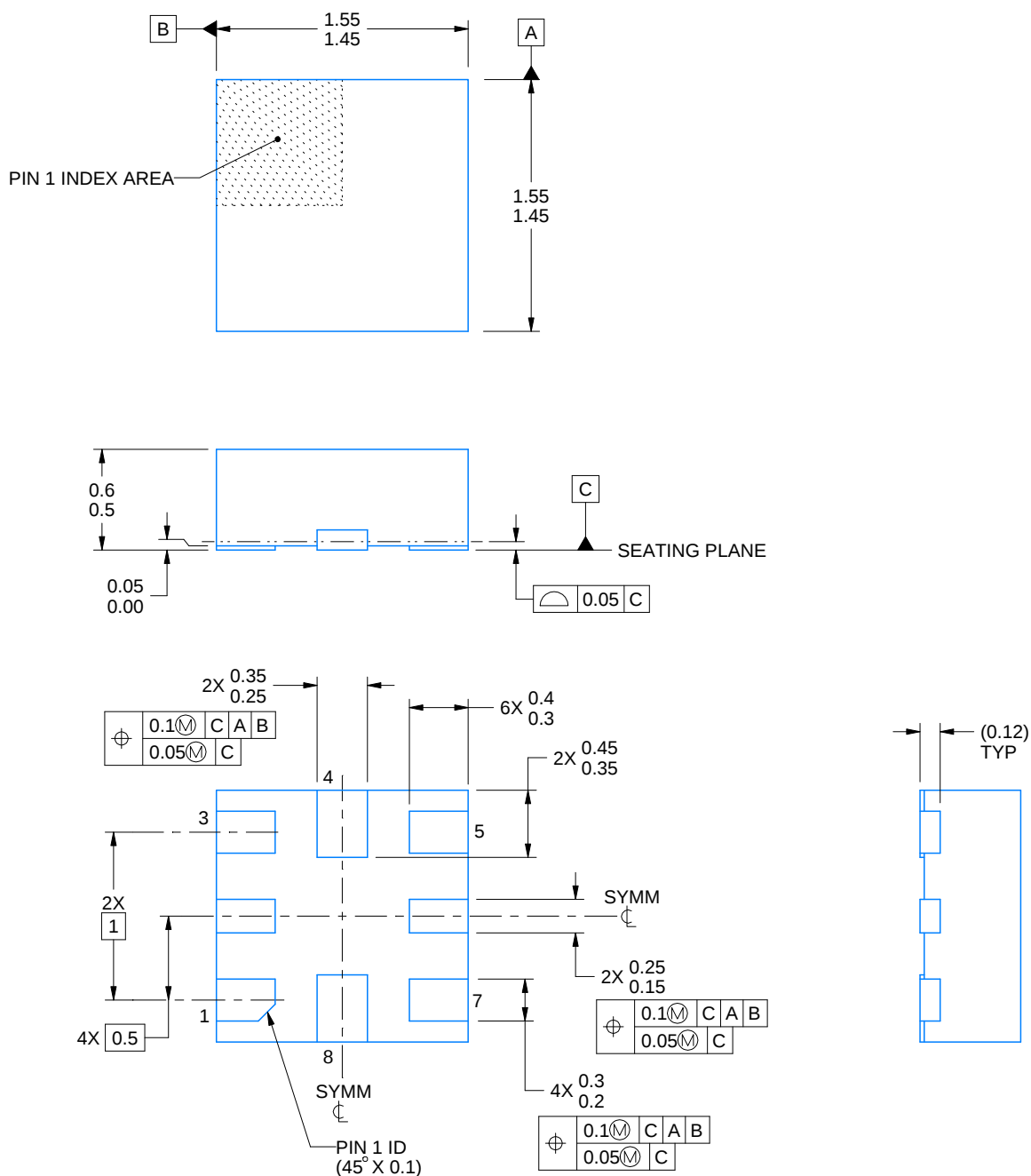
5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PACKAGE OUTLINE

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4220323/B 03/2018

NOTES:

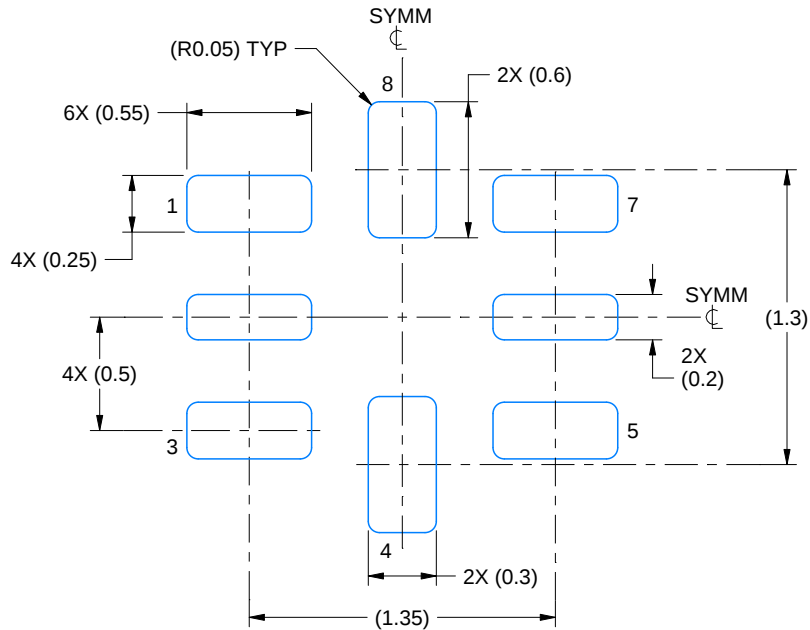
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

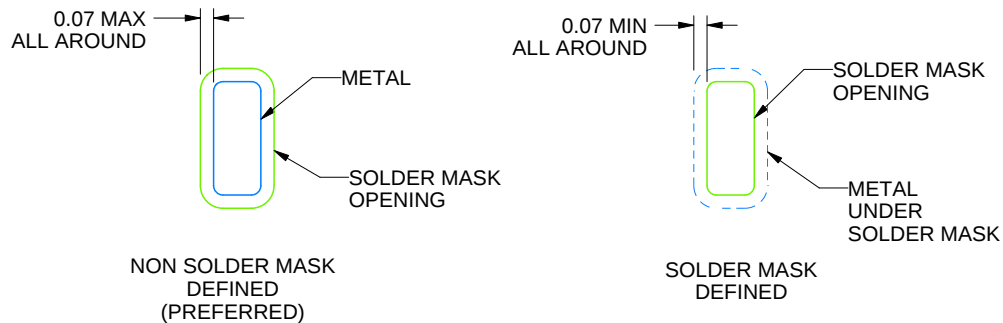
RSE0008A

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:30X



SOLDER MASK DETAILS
NOT TO SCALE

4220323/B 03/2018

NOTES: (continued)

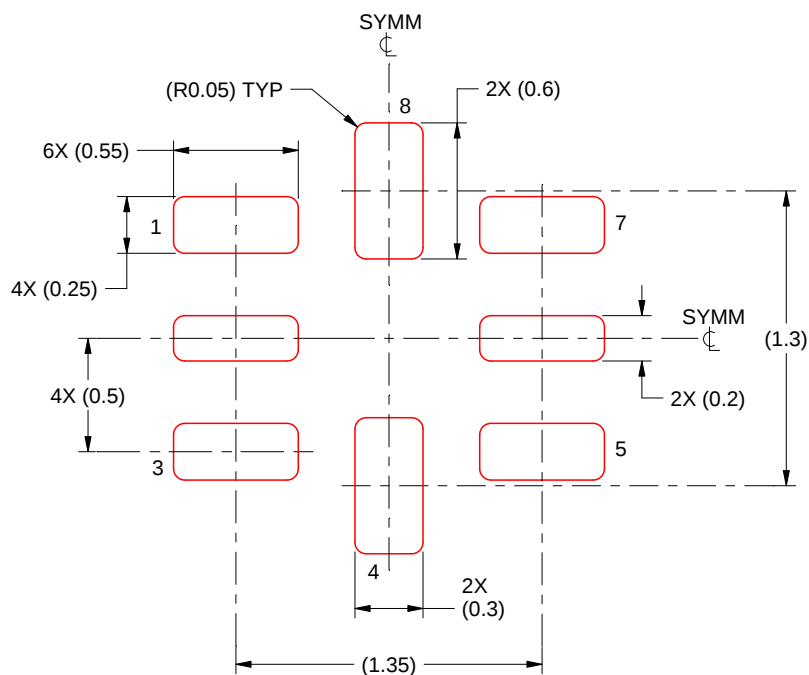
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

RSE0008A

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICKNESS
SCALE: 30X

4220323/B 03/2018

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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